



Micro Commercial Components

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# BUT11A

## NPN Silicon Power Transistors

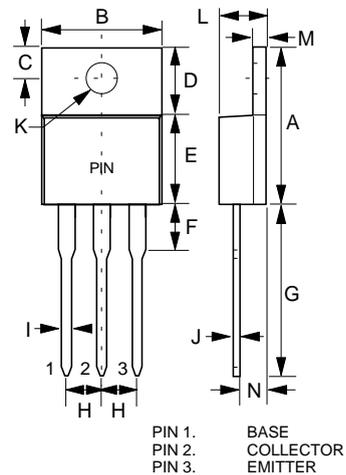
### Features

- High voltage, high speed NPN power transistors.
- With TO-220 package
- Intended for use in converters, inverters, switching regulators, motor control systems.

### Maximum Ratings

Symbol	Rating	Rating	Unit
$V_{CE0}$	Collector-Emitter Voltage	450	V
$V_{CBO}$	Collector-Base Voltage	1000	V
$V_{EBO}$	Emitter to Base Voltage	9.0	V
$I_{CP}$	Peak Collector Current	10	A
$I_C$	Collector Current	5.0	A
$P_C$	Collector power dissipation	100	W
$T_J$	Junction Temperature	-55 to +150	$^{\circ}C$
$T_{STG}$	Storage Temperature	-55 to +150	$^{\circ}C$

### TO-220



### Electrical Characteristics @ 25°C Unless Otherwise Specified

Symbol	Parameter	Min	Max	Units
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#### OFF CHARACTERISTICS

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage ( $I_C=100mA_{dc}$ , $I_B=0$ )	450	---	Vdc
$I_{CBO}$	Collector-Base Cutoff Current ( $V_{CB}=1000V_{dc}$ , $I_E=0$ )	---	1.0	mAdc
$I_{EBO}$	Emitter-Base Cutoff Current ( $V_{EB}=9.0V_{dc}$ , $I_C=0$ )	---	10	mAdc

#### ON CHARACTERISTICS

$h_{FE-1}$	Forward Current Transfer ratio ( $I_C=5.0mA_{dc}$ , $V_{CE}=5.0V_{dc}$ )	10	35	---
$h_{FE-2}$	Forward Current Transfer ratio ( $I_C=500mA_{dc}$ , $V_{CE}=5.0V_{dc}$ )	10	35	---
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ( $I_C=2.5A_{dc}$ , $I_B=0.5A_{dc}$ )	---	1.5	Vdc
$V_{BE(sat)}$	Base-Emitter Saturation Voltage ( $I_C=2.5A_{dc}$ , $I_B=0.5A_{dc}$ )	---	1.3	Vdc

#### DIMENSIONS

DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.560	.625	14.22	15.88	
B	.380	.420	9.65	10.67	
C	.100	.135	2.54	3.43	
D	.230	.270	5.84	6.86	
E	.380	.420	9.65	10.67	
F	-----	.250	-----	6.35	
G	.500	.580	12.70	14.73	
H	.090	.110	2.29	2.79	
I	.020	.045	0.51	1.14	
J	.012	.025	0.30	0.64	
K	.139	.161	3.53	4.09	∅
L	.140	.190	3.56	4.83	
M	.045	.055	1.14	1.40	
N	.080	.115	2.03	2.92	